

## Product Summary

- $V_{DS} = 600V, I_D = 4A$
- $R_{DS(on)} < 2.3\Omega$  @  $V_{GS} = 10V$

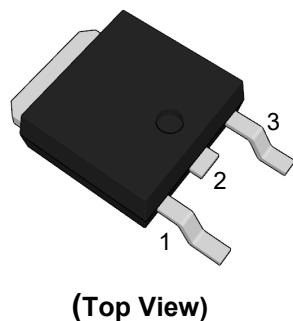
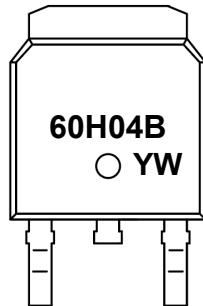
## Features

- Advanced Planar Technology
- 100% Avalanche Tested
- RoHS Compliant
- Halogen and Antimony Free
- Moisture Sensitivity Level 3

## Application

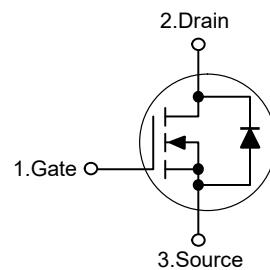
- AC-DC Switching Power Supplies
- DC-DC Power Converter
- High Voltage High-Bridge PWM Motor Driver

## Marking Code



Pin	Description
1	Gate
2	Drain
3	Source

## Schematic Diagram



## Absolute Maximum Ratings

Ratings at 25°C case temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	600	V
Gate-Source Voltage	$V_{GS}$	$\pm 30$	V
Drain Current-Continuous	$I_D$	4	A
Drain Current-Pulsed <sup>Note1</sup>	$I_{DM}$	16	A
Maximum Power Dissipation	$P_D$	147	W
Single Pulse Avalanche Energy <sup>Note2</sup>	$E_{AS}$	170	mJ
Junction Temperature	$T_J$	150	°C
Storage Temperature Range	$T_{STG}$	-55 to +150	°C

## Thermal Characteristics

Thermal Resistance, Junction-to-Case	$R_{eJC}$	0.85	°C/W
--------------------------------------	-----------	------	------

## Electrical Characteristics

(T<sub>J</sub>=25°C unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
<b>Off characteristics</b>						
BV <sub>DSS</sub>	Drain to source breakdown voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	600			V
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown voltage temperature coefficient	I <sub>D</sub> =250uA, referenced to 25°C		0.5		V/°C
I <sub>DSS</sub>	Drain to source leakage current	V <sub>DS</sub> =610V, V <sub>GS</sub> =0V			1	uA
		V <sub>DS</sub> =488V, T <sub>C</sub> =125°C			50	uA
I <sub>GSS</sub>	Gate to source leakage current, forward	V <sub>GS</sub> =30V, V <sub>DS</sub> =0V			100	nA
	Gate to source leakage current, reverse	V <sub>GS</sub> =-30V, V <sub>DS</sub> =0V			-100	nA
<b>On characteristics</b>						
V <sub>GS(TH)</sub>	Gate threshold voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	2.5		4.5	V
R <sub>DS(ON)</sub>	Drain to source on state resistance	V <sub>GS</sub> =10V, I <sub>D</sub> = 2A		2	2.2	Ω
G <sub>f</sub> s	Forward Transconductance	V <sub>DS</sub> = 30 V, I <sub>D</sub> = 2A		3.3		S
<b>Dynamic characteristics</b>						
C <sub>iss</sub>	Input capacitance	V <sub>GS</sub> =0V, V <sub>DS</sub> =25V, f=1MHz		586		pF
C <sub>oss</sub>	Output capacitance			71		
C <sub>rss</sub>	Reverse transfer capacitance			7.6		
t <sub>d(on)</sub>	Turn on delay time	V <sub>DS</sub> =300V, I <sub>D</sub> =4A, R <sub>G</sub> =25Ω (note 4,5)		12		ns
t <sub>r</sub>	Rising time			27		
t <sub>d(off)</sub>	Turn off delay time			33		
t <sub>f</sub>	Fall time			25		
Q <sub>g</sub>	Total gate charge	V <sub>DS</sub> =480V, V <sub>GS</sub> =10V, I <sub>D</sub> =4A (note 4,5)		17		nC
Q <sub>gs</sub>	Gate-source charge			8		
Q <sub>gd</sub>	Gate-drain charge			5		

## Source to drain diode ratings characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I <sub>S</sub>	Continuous source current	Integral reverse p-n Junction diode in the MOSFET			4	A
I <sub>SM</sub>	Pulsed source current				16	A
V <sub>SD</sub>	Diode forward voltage drop.	I <sub>S</sub> =4A, V <sub>GS</sub> =0V			1.5	V
T <sub>rr</sub>	Reverse recovery time	I <sub>S</sub> =4A, V <sub>GS</sub> =0V, dI <sub>F</sub> /dt=100A/us		366		ns
Q <sub>rr</sub>	Reverse recovery Charge			1.9		uC

## ※. Notes

1. Repetitive rating : pulse width limited by junction temperature.
2. L = 21mH, I<sub>AS</sub> = 4A, V<sub>DD</sub> = 50V, R<sub>G</sub>=25Ω, Starting T<sub>J</sub> = 25°C
3. I<sub>SD</sub> ≤ 4A, di/dt = 100A/us, V<sub>DD</sub> ≤ BV<sub>DSS</sub>, Starting T<sub>J</sub> =25°C
4. Pulse Test : Pulse Width ≤ 300us, duty cycle ≤ 2%.
5. Essentially independent of operating temperature.

## Typical Characteristic Curves

Fig. 1. On-state characteristics

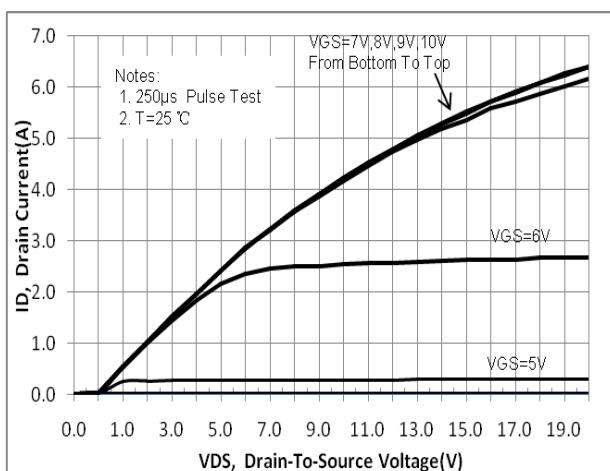


Fig. 2. On-resistance variation vs. drain current and gate voltage

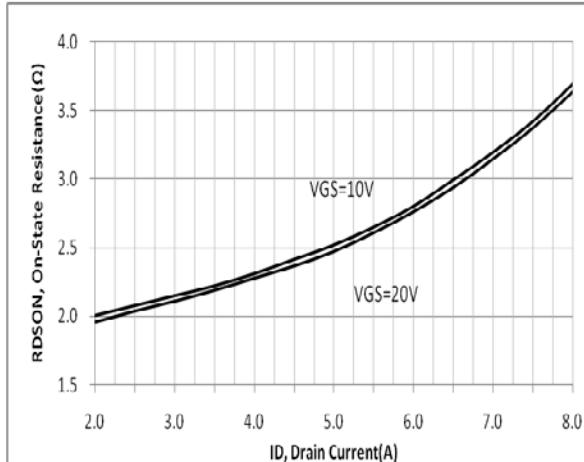


Fig. 3. Gate charge characteristics

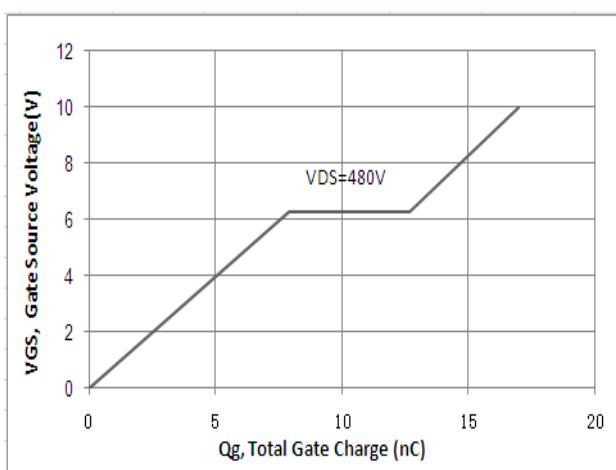


Fig. 4. On state current vs. diode forward voltage

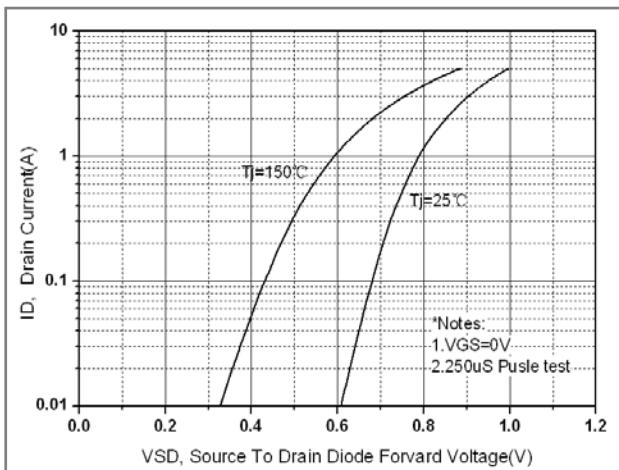


Fig. 5. Breakdown Voltage Variation vs. Junction Temperature

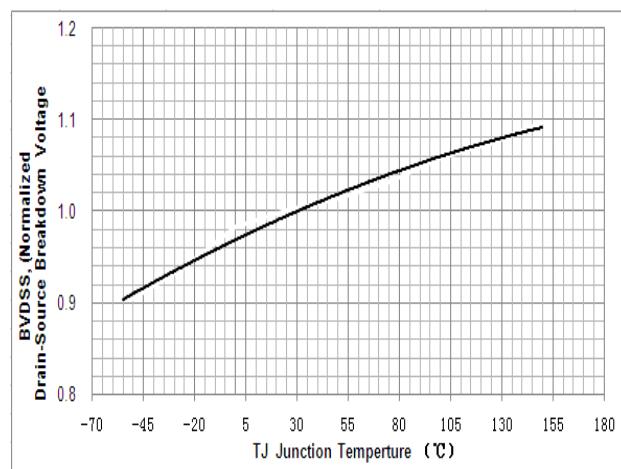


Fig. 6. On resistance variation vs. junction temperature

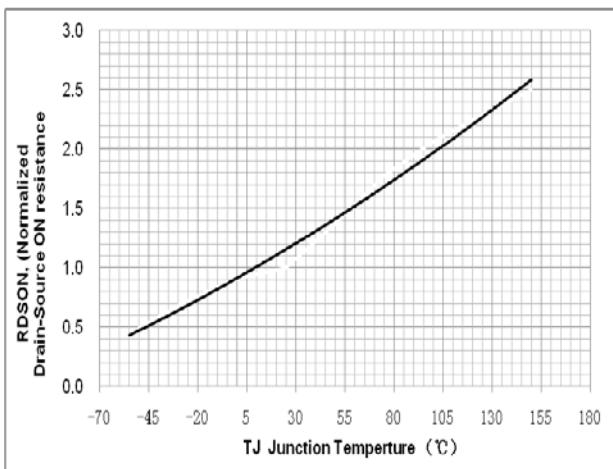


Fig. 7. Maximum safe operating area ( TO-251 )

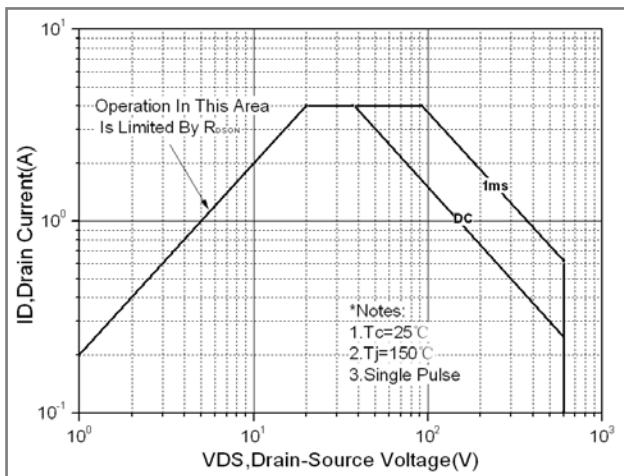


Fig. 8. Transient thermal response curve ( TO-251 )

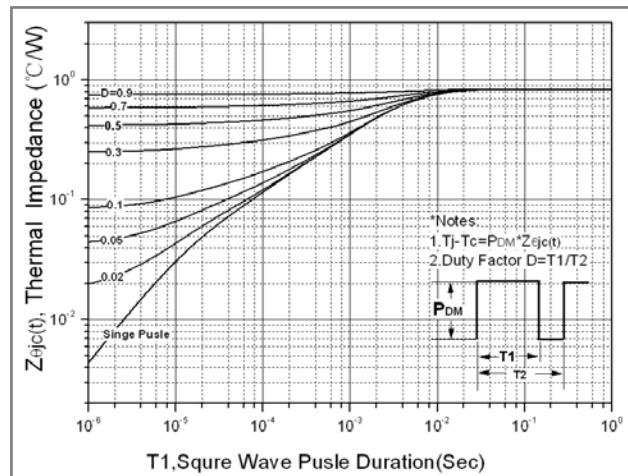


Fig. 9. Maximum safe operating area ( TO-252 )

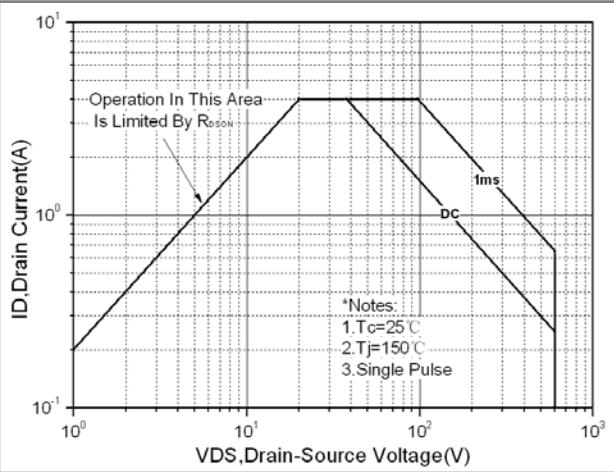


Fig. 10. Transient thermal response curve ( TO-252 )

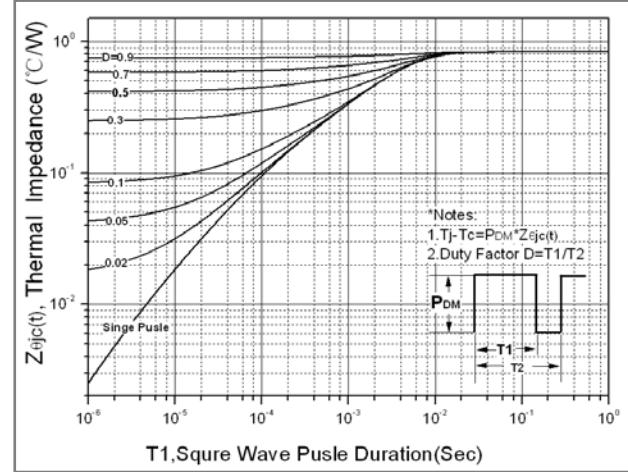
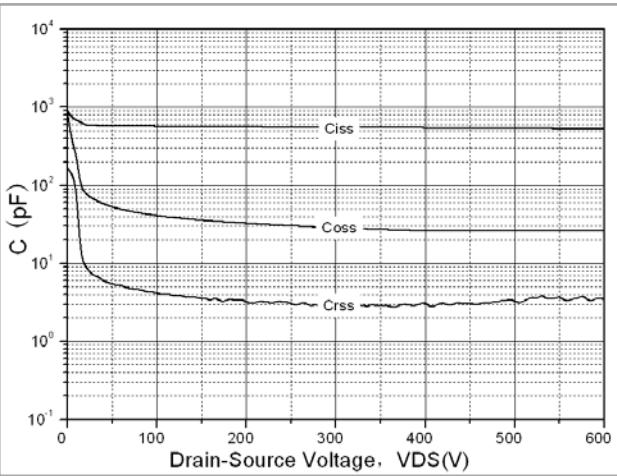


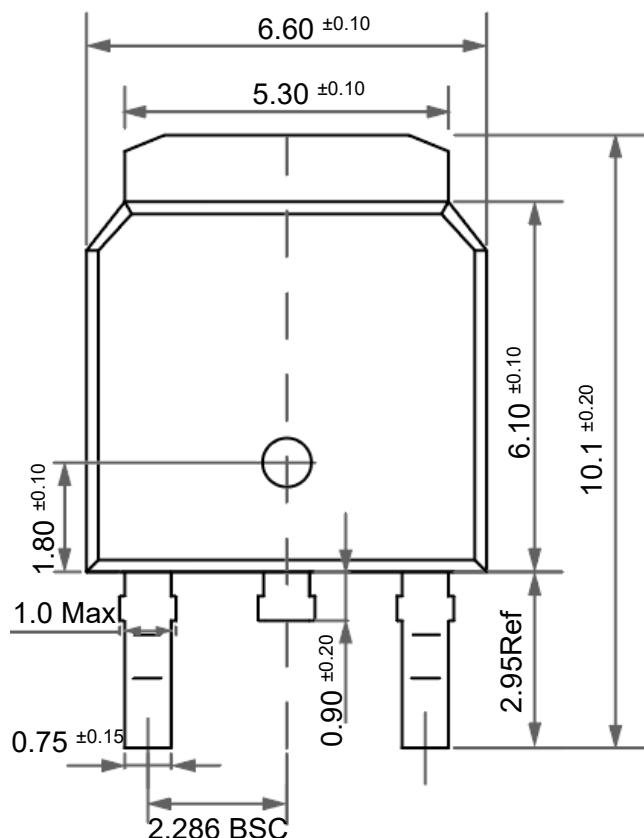
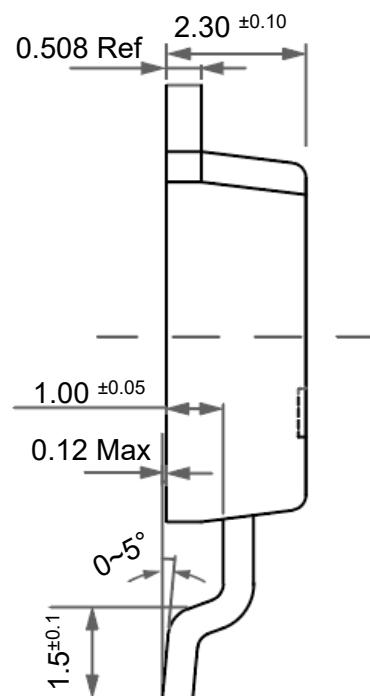
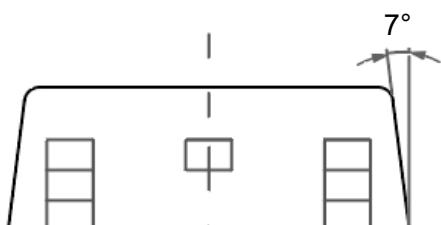
Fig. 11. Capacitance Characteristics



**Package Outline**

TO-252

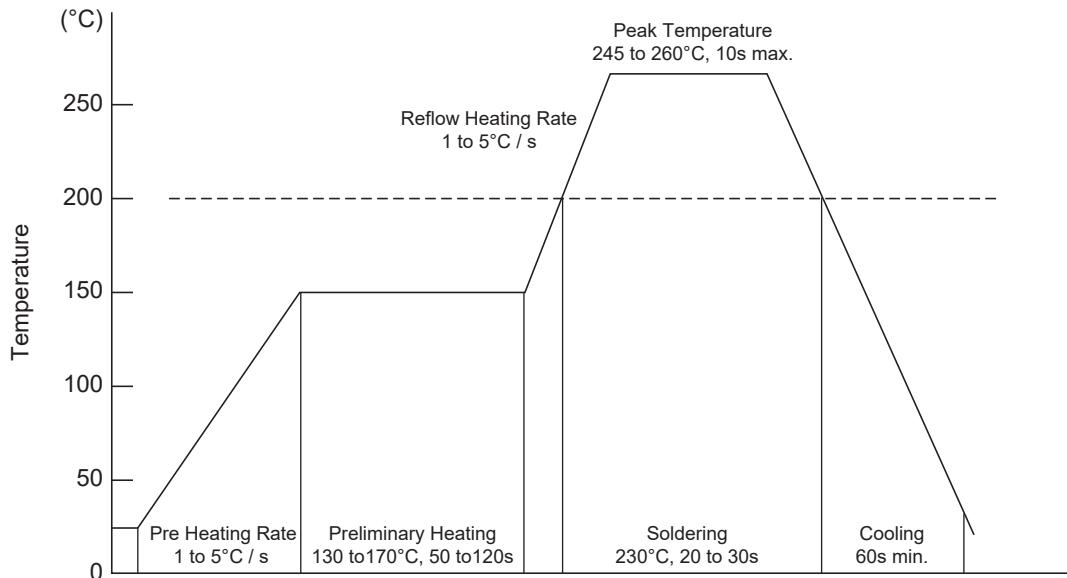
Dimensions in mm

**Front View****Side View****Bottom View****Ordering Information**

Device	Package	Shipping
TN60H04BNTE	TO-252	2,500PCS/Reel&13inches

## Conditions of Soldering and Storage

### ◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245°C. If peak temperature is below 245°C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

### ◆ Conditions of hand soldering

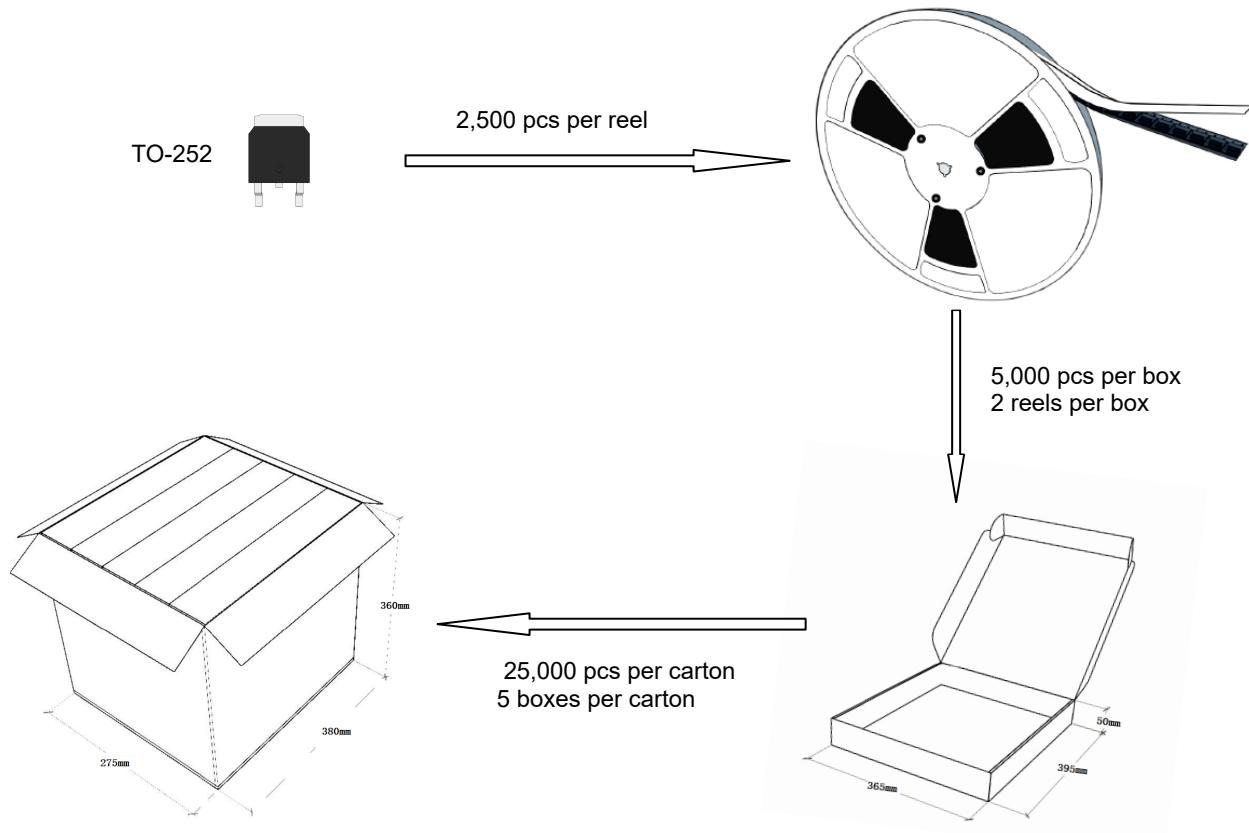
- Temperature: 300°C
- Time: 3s max.
- Times: one time

### ◆ Storage conditions

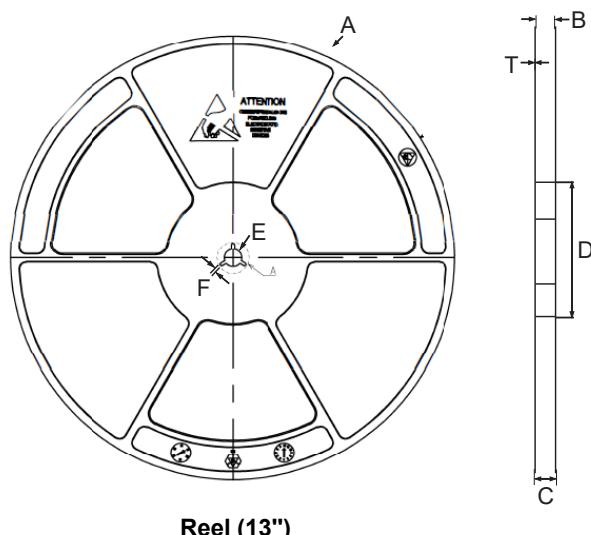
- **Temperature**  
5 to 40°C
- **Humidity**  
30 to 80% RH
- **Recommended period**  
One year after manufacturing

## Package Specifications

- The method of packaging

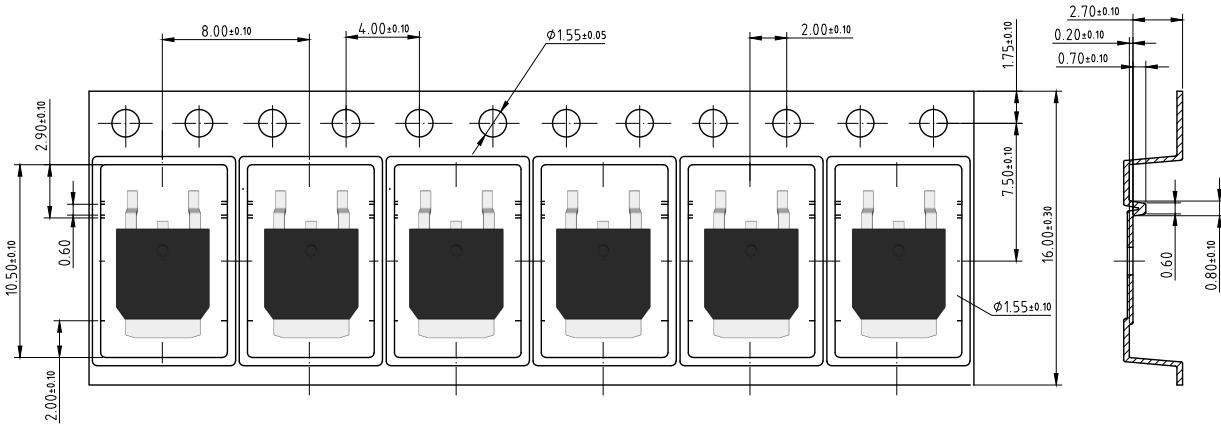


### ◆ reel data



Symbol	Value(unit:mm)
A	$\Phi 330.2 \pm 1$
B	$17 \pm 0.5$
C	$21.2 \pm 2$
D	$\Phi 100 \pm 0.5$
E	$\Phi 13.4 \pm 0.2$
F	$2.3 \pm 0.2$
T	$2.1 \pm 0.2$

◆ Embossed tape data



## Contact Information

TANI website: <http://www.tanisemi.com> Email:tani@tanisemi.com

For additional information, please contact your local Sales Representative.



® is registered trademarks of TANI Corporation.

### Product Specification Statement

The product specification aims to provide users with a reference regarding various product parameters, performance, and usage. It presents certain aspects of the product's performance in graphical form and is intended solely for users to select product and make product comparisons, enabling users to better understand and evaluate the characteristics and advantages of the product. It does not constitute any commitment, warranty, or guarantee.

The product parameters described in the product specification are numerical values, characteristics, and functions obtained through actual testing or theoretical calculations of the product in an independent or ideal state. Due to the complexity of product applications and variations in test conditions and equipment, there may be slight fluctuations in parameter test values. TANI shall not guarantee that the actual performance of the product when installed in the customer's system or equipment will be entirely consistent with the product specification, especially concerning dynamic parameters. It is recommended that users consult with professionals for product selection and system design. Users should also thoroughly validate and assess whether the actual parameters and performance when installed in their respective systems or equipment meet their requirements or expectations. Additionally, users should exercise caution in verifying product compatibility issues, and TANI assumes no responsibility for the application of the product. TANI strives to provide accurate and up-to-date information to the best of our ability. However, due to technical, human, or other reasons, TANI cannot guarantee that the information provided in the product specification is entirely accurate and error-free. TANI shall not be held responsible for any losses or damages resulting from the use or reliance on any information in these product specifications.

TANI reserves the right to revise or update the product specification and the products at any time without prior notice, and the user's continued use of the product specification is considered an acceptance of these revisions and updates. Prior to purchasing and using the product, users should verify the above information with TANI to ensure that the product specification is the most current, effective, and complete. If users are particularly concerned about product parameters, please consult TANI in detail or request relevant product test reports. Any data not explicitly mentioned in the product specification shall be subject to separate agreement.

Users are advised to pay attention to the parameter limit values specified in the product specification and maintain a certain margin in design or application to ensure that the product does not exceed the parameter limit values defined in the product specification. This precaution should be taken to avoid exceeding one or more of the limit values, which may result in permanent irreversible damage to the product, ultimately affecting the quality and reliability of the system or equipment.

The design of the product is intended to meet civilian needs and is not guaranteed for use in harsh environments or precision equipment. It is not recommended for use in systems or equipment such as medical devices, aircraft, nuclear power, and similar systems, where failures in these systems or equipment could reasonably be expected to result in personal injury. TANI shall assume no responsibility for any consequences resulting from such usage.

Users should also comply with relevant laws, regulations, policies, and standards when using the product specification. Users are responsible for the risks and liabilities arising from the use of the product specification and must ensure that it is not used for illegal purposes. Additionally, users should respect the intellectual property rights related to the product specification and refrain from infringing upon any third-party legal rights. TANI shall assume no responsibility for any disputes or controversies arising from the above-mentioned issues in any form.